Enhanced linear and nonlinear optical phase response of AlGaAs microring resonators

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We have constructed and characterized several optical microring resonators with scale sizes of the order of 10 μm. These devices are intended to serve as building blocks for engineerable linear and nonlinear photonic media. Light is guided vertically by an epitaxially grown structure and transversely by deeply etched air-clad sidewalls. We report on the spectral phase transfer characteristics of such resonators. We also report the observation of a π-rad Kerr nonlinear phase shift accumulated in a single compact ring resonator evidenced by all-optical switching between output ports of a resonator-enhanced Mach–Zehnder interferometer. © 2004 Optical Society of America

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In recent years optical microring resonators have become an intense area of active research. Much of this activity centers on a potential for highly compact add–drop filter networks,1,2 dispersion compensators,3 delay lines,4 and sensors.5,6 Microring resonators can also serve as key elements in the realization of engineerable photonic media. A sequence of resonators coupled to an optical waveguide can be viewed as an optical transmission line with highly controllable dispersive and nonlinear properties similar to those of photonic crystals. In previous articles7,8 many applications of photonic crystals. In previous articles7,8 many applications of these artificial channels were proposed ranging from soliton propagation on a chip to miniaturized all-optical switches, delay lines, and pulse compressors. Most of these applications require nonlinear phase shifts near π rad to become practical, and such was the goal of this experimental work.

Recently, all-optical switching in a single GaAs-guiding microresonator was observed for the first time.9 In this work we chose to construct ring resonators in AlGaAs and probe them at a photon energy (hc/λ = 0.8 eV) below the half-gap (Eg/2 = 0.97 eV) of the material. Our motivation for this choice was to maximize the ultrafast bound (Kerr) nonlinearities resulting from virtual transitions while minimizing the two-photon contribution to carrier generation.10 Although this effect is a relatively weak nonlinearity requiring higher circulating intensities than in the previous work, the deposition of heat resulting from two-photon absorption can be substantially minimized. In addition, the lower limit of response time is dictated by the cavity lifetime only and not the carrier recombination lifetime.

Ring resonators are ideal candidates for the miniaturization of photonic devices because they have the ability to recycle light through feedback and thus demand less physical path length to exhibit certain linear optical effects. The coherent buildup of intensity circulating within the resonator further reduces the required path length (or intensity) for accessing traditionally weak nonlinear optical effects. Applied to the case of Kerr nonlinear phase accumulation, which scales with the product of length and intensity, it has been shown that nonlinear phase shifts are enhanced in proportion to the square of the resonator finesse.11

The transmission of a microring-based add–drop resonator can be modeled according to

\[ T = \frac{r_2^2 - 2r_1r_2 \cos \phi + r_1^2}{1 - 2r_1r_2 \cos \phi + r_1^2 r_2^2}, \] (1)

where \( \phi = T_R \Delta \omega \) is the detuning \( \Delta \omega \) from resonance normalized by the ring transit time \( T_R \), and \( r_1 \) and \( r_2 \) are the self-coupling coefficients. The resonator finesse is given by \( F = \pi/(1 - r_1r_2) \). Setting \( r_2 = 1 \) is equivalent to removing one of the coupled waveguides and results in the classic all-pass, phase-only resonator. While maintaining a unit-amplitude transmission spectrum, the transmitted phase of this device varies as

\[ \Phi = \pi + \phi + 2 \arctan \left( \frac{r \sin \phi}{1 - r \cos \phi} \right). \] (2)

Because of an increased phase sensitivity (or increased effective path length) near resonance, the resonator need only be detuned by \( 2\pi/F \) rad to achieve a net transmitted phase shift of \( \pi \). Furthermore, the power threshold requirement to achieve this detuning by means of an intensity-dependent refractive-index change is reduced by a circulating intensity buildup of \( B = 2F/\pi \) so that

\[ P_{\text{threshold}} = \frac{\pi \lambda A_{\text{eff}}}{2n_2 L F^2}, \] (3)
Fig. 1. Design of the resonator structures investigated in this work. The vertical structure is formed by molecular-beam epitaxy, and the horizontal structure by nanolithography. All dimensions are in micrometers.

Fig. 2. Procedure used to fabricate the microresonators. MBE, molecular-beam epitaxy; RIE, reactive-ion etch; e-beam, electron-beam.

where \( A_{\text{eff}} \) is the effective mode area and \( L \) is the circumference. For a typical AlGaAs channel waveguide with a nonlinear coefficient of \( n_2 = 10^{-12} \text{ m}^2/\text{W} \), an effective mode area of \( 0.5 \mu\text{m}^2 \), a ring diameter of \( 10 \mu\text{m} \), and a finesse of 10, the threshold peak power is approximately \( 40 \text{ W} \) at \( 1.55 \mu\text{m} \). Note that in comparison with standard single-mode silica fiber with a threshold power–length product of 500 Wm, this situation corresponds to \( 1200 \text{ W}\mu\text{m} \). This reduction of an order of magnitude is attributed to a stronger nonlinear coefficient, a tighter mode area, and resonant enhancement.

Fig. 3 displays scanning electron microscopy images of two of the fabricated devices. The narrow gap region was extended along the propagation direction by \( 4 \mu\text{m} \) into a racetrack geometry to increase the guide-to-ring coupling. Devices with varying gap width were fabricated and the best were selected during characterization.

To deliver light to the microresonator-based devices, the bus waveguides were tapered out to cleaved sample edges for a total sample length of 1 mm. Light was end-fire coupled into the tapered waveguides and collected at the other end with \( 40 \times \) microscope objectives. A polarization controller was used to select TM excitation (field perpendicular to the plane of the ring). Spectral characterization of the microresonators was performed with a tunable diode laser near \( 1.55 \mu\text{m} \).

Figure 4 displays the spectral transmission data for the through port of the add–drop resonator in Fig. 3(a). Here, a racetrack resonator of \( 12.5-\mu\text{m} \) radius with extended straight segments coupled to two waveguides on either side has a measured bandwidth of 110 GHz, a free spectral range of 1.1 THz, and a finesse of approximately 10 (\( Q = 1760 \)). Scattering-limited losses resulting from sidewall roughness are estimated at 10% per round trip.

Figure 5 displays the spectral transmission data for an output port of a nearly balanced Mach–Zehnder interferometer containing an all-pass resonator in one arm, as shown in Fig. 3(b). In this configuration the overcoupled phase response of the 5-\( \mu\text{m} \) radius racetrack resonator could be inferred from the amplitude response of the composite resonator-enhanced Mach–Zehnder (REMZ) interferometer. A

Fig. 4. Measured transmission spectrum of the microresonator shown in Fig. 3(a) with a theoretical fit.

Fig. 5. Scanning electron microscopy images of (a) an add–drop ring resonator and (b) an all-pass ring resonator coupled to one arm of a Mach–Zehnder interferometer.
measured bandwidth of 240 GHz and a free spectral range of 2.3 THz results in a finesse of approximately 10 (Q = 810), which is dictated primarily by the coupling. Scattering-limited losses are estimated at 11% per round trip. Also displayed in the figure is the phase response obtained from a fit to the data that displays increased sensitivity near each of the two resonances.

Next, the intensity-dependent transmission of the REMZ interferometer was measured with a 10-Hz 30-ps Nd:YAG-pumped optical parametric generator (Ekspla) source at 1.545 μm. The low average power of the source ensured that thermal effects could be ignored. Optical self-switching was clearly observed in some samples. Figure 6 displays transverse slices of the imaged outputs of the REMZ interferometer in Fig. 3(b). Three traces are shown, each with increasing pulse energies. Incomplete extinction resulted from higher losses in the arm containing the ring. The actual pulse energies injected into the resonators were of the order of 1 nJ. The relative distribution of output power is clearly seen to shift from one output guide to the other as the pulse energy is increased, implying a phase-shift advance of approximately π rad.

In conclusion, we have demonstrated the potential of ring resonators as nonlinear phase-shifting elements for photon energies below the half-gap. At these energies optical nonlinearities are essentially instantaneous, and one- and two-photon absorption and carrier generation are negligible. Our experiments show that previous demonstrations of large nonlinear phase shifts in 5-mm or longer waveguide lengths can be compressed into devices 100 or more times shorter. Ultracompact devices constructed from these building blocks have the potential to be engineered into ultrafast nonlinear photonic devices that generate negligible heat. For example, a device similar to the one presented in this Letter with a finesse of 100 could support 12.5-ps pulses and switch with energies as low as 4 pJ. Further optimization of the guiding confinement area and nonlinear response can produce devices with a 1-THz bandwidth and a 1-pJ energy threshold.

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